NSN 5962-01-171-5595



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-171-5595 **Body Length:** 0.520 inches **Body Width:** 0.390 inches **Body Height:** 0.085 inches **Maximum Power Dissipation Rating:** 715.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and programmable and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 125.00 nanoseconds propagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 82577-932892 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 flat leads Shelf Life: N/a **Unit Of Measure:**

Fiig:

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Demilitarization: Yes - demil/mli